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Author Correction: The effects of point defect type, location, and density on the Schottky barrier height of Au/MoS₂ heterojunction: a first-principles study

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In the original version of this Article, Kah-Wee Ang and Yong-Wei Zhang were omitted as corresponding authors. Correspondence and requests for materials should also be addressed to kahwee.ang@nus.edu.sg and zhangyw@ihpc.a-star.edu.sg

The original Article has been corrected.



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